

## **Description**

The IRFR3806PBF uses advanced trench technology to provide excellent R<sub>DS(ON)</sub>, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.



TO-252-2L

## **General Features**

 $V_{DS} = 60V I_{D} = 50 A$ 

 $R_{DS(ON)}$  < 17m $\Omega$  @  $V_{GS}$ =10V

## **Application**

Battery protection

Load switch

Uninterruptible power supply

# PIN1 G PIN3 S

N-Channel MOSFET

# Package Marking and Ordering Information

Product ID	Pack	Brand	Qty(PCS)
IRFR3806PBF	TO-252-2L	HXY MOSFET	2500

# Absolute Maximum Ratings (T<sub>C</sub>=25°Cunless otherwise noted)

Symbol	Parameter	Rating	Units	
V <sub>D</sub> s	Drain-Source Voltage	60	V	
Vgs	Gate-Source Voltage	±20	V	
I <sub>D</sub> @T <sub>C</sub> =25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	V <sup>1</sup> 50		
I <sub>D</sub> @T <sub>C</sub> =100°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	ain Current, V <sub>GS</sub> @ 10V <sup>1</sup> 38		
Ірм	Pulsed Drain Current <sup>2</sup>	urrent <sup>2</sup> 180		
EAS	Single Pulse Avalanche Energy <sup>3</sup>	280	mJ	
las	Avalanche Current	28	А	
P <sub>D</sub> @T <sub>C</sub> =25°C	Total Power Dissipation <sup>4</sup>	87.7	W	
Тѕтс	Storage Temperature Range	-55 to 150	°C	
TJ	Operating Junction Temperature Range	-55 to 150 °C		
R <sub>θ</sub> JA	Thermal Resistance Junction-Ambient <sup>1</sup>	62 °C/M		



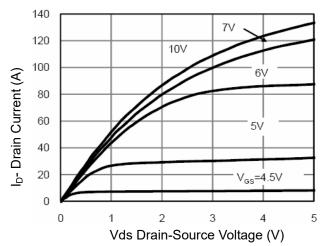
# Electrical Characteristics (T<sub>C</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	60	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =60V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS},I_{D}=250\mu A$	1.0	1.5	2.5	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =30A	-	13	17	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =5V,I <sub>D</sub> =30A	30	-	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	C <sub>lss</sub>	.,	-	2498	-	PF
Output Capacitance	Coss	$V_{DS}=25V, V_{GS}=0V,$	-	185	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz	-	80	-	PF
Switching Characteristics (Note 4)			•			•
Turn-on Delay Time	t <sub>d(on)</sub>		-	12	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =30V, $I_D$ =2A, $R_L$ =1 $\Omega$	-	5.2	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =10 $V$ , $R_{GEN}$ =3 $\Omega$	-	38	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	27	-	nS
Total Gate Charge	Qg	\/ 20\/ L 20A	-	36	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}=30V,I_{D}=30A,$ $V_{GS}=10V$	-	9.9	-	nC
Gate-Drain Charge	$Q_{gd}$	V <sub>GS</sub> -10V	-	6.6	-	nC
Drain-Source Diode Characteristics			•			•
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =30A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	58	Α
Reverse Recovery Time	t <sub>rr</sub>	TJ = 25°C, IF =30A	-	35		nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs <sup>(Note3)</sup>	-	47		nC
Forward Turn-On Time	t <sub>on</sub>	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

### Notes:

- **1.** Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.**  $E_{AS}$  condition:  $Tj=25\,^{\circ}\mathrm{C}$ , $V_{DD}=30V$ , $V_{G}=10V$ ,L=0.5mH, $Rg=25\Omega$

# **Typical Electrical and Thermal Characteristics (Curves)**



**Figure 1 Output Characteristics** 

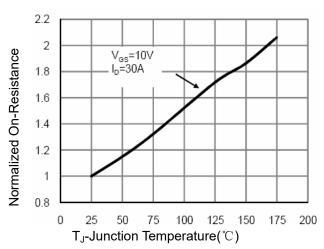
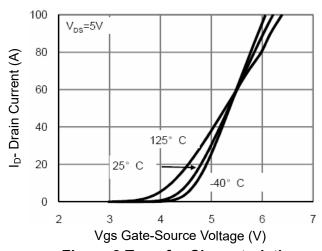


Figure 4 Rdson-JunctionTemperature



**Figure 2 Transfer Characteristics** 

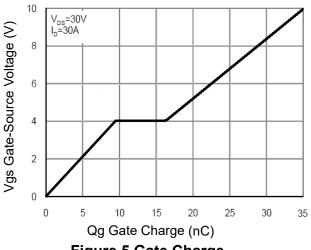


Figure 5 Gate Charge

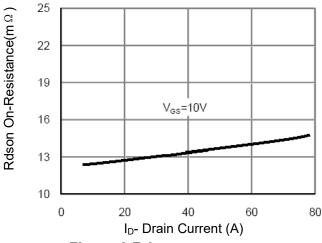


Figure 3 Rdson- Drain Current

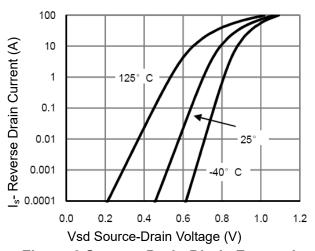
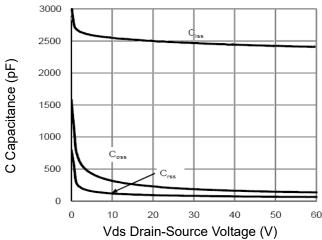


Figure 6 Source- Drain Diode Forward



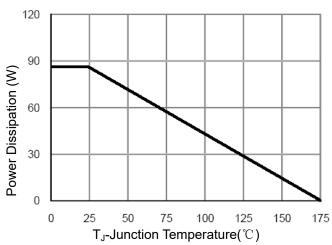
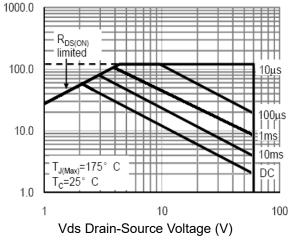


Figure 7 Capacitance vs Vds





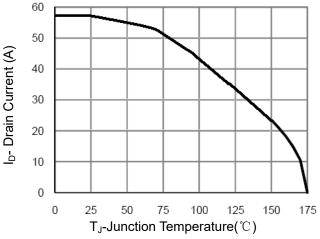
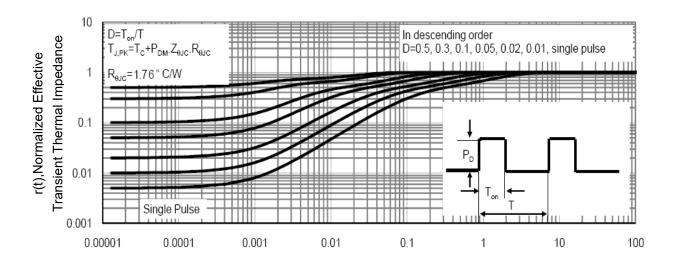
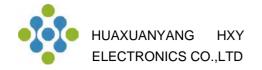


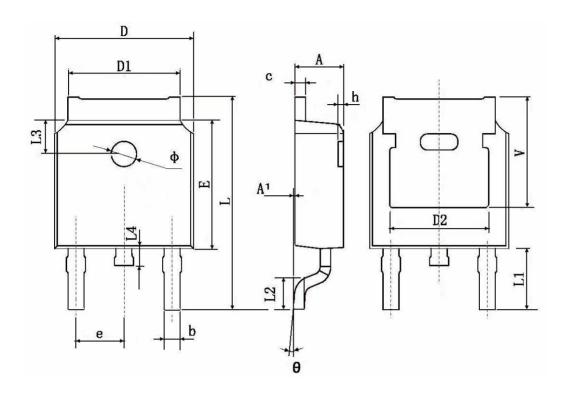
Figure 8 Safe Operation Area

Figure 10 ID Current- JunctionTemperature





# **TO-252-2L Package Information**



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	0.483 TYP.		0.190 TYP.		
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350 TYP.		0.211 TYP.		



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